

STBR3012L2Y-TR

Datasheet

Automotive high voltage rectifier for bridge applications

HU³PAK

Product status link

STBR3012L2Y-TR

Features



- Ultra low conduction losses
- Ultra-low reverse losses
- High junction temperature capability (+175 °C)
- V_{RRM} guaranteed from -40 to +175 °C
- PPAP capable
- ECOPACK2 compliant

Application

- On board charger
 - Bridge

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Product summary Symbol Value IF(AV) 30 A VRRM 1200 V Tj +175 °C

0.95 V

V_F (typ.)

Description

The high quality design of this diode has produced a device with consistently reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability like automotive applications.

Thanks to its ultra-low conduction losses, the STBR3012L2Y-TR is especially suitable for use as input bridge diode in battery chargers.



1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V _{RSM}	Non-repetitive surge reverse voltage	on-repetitive surge reverse voltage		V
V _{RRM}	Repetitive peak reverse voltage	Repetitive peak reverse voltage $T_j = -40 \degree C$ to +175 $\degree C$		V
I _{F(RMS)}	Forward rms current	current		А
I _{F(AV)}	Average forward current, $\delta = 0.5$ square wave	T _C = 150 °C	30	А
I _{FSM}	Surge non repetitive forward current	n repetitive forward current t_p = 10 ms sinusoidal		А
T _{stg}	Storage temperature range	rage temperature range		°C
Тj	Operating junction temperature		-40 to +175	°C

Table 2. Thermal parameters

Symbol	Parameter	Typ. value	Unit
R _{th(j-c)}	Junction to case	0.45	°C/W

For more information you can refer to:

TN1378: HU3PAK package mounting and thermal behavior.

Table 3. Static electrical characteristics

Symbol	Parameter	Test co	Min.	Тур.	Max.	Unit	
L (1)	Reverse leakage current	T _j = 25 °C		-		2	μA
$I_{R}^{(1)}$		T _j = 150 °C	V _R = V _{RRM}	-	10	100	
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 30 A	-	1.05	1.3	V
		T _j = 150 °C	1 _F = 30 A	-	0.95	1.2	

1. Pulse test: $t_p = 5 ms$, $\delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses, use the following equation:

 $P = 0.96 \text{ x } I_{F(AV)} + 0.008 \text{ x } I_{F}^{2}(RMS)$

For more information, you can refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses in a power diode



1.1 Characteristics (curves)

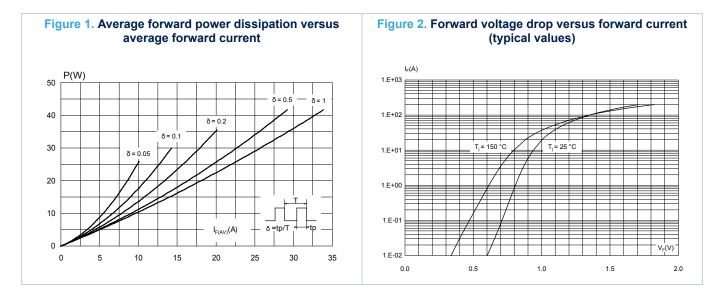
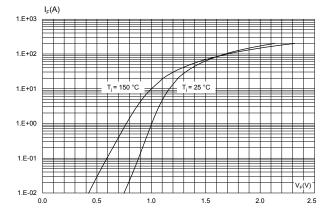


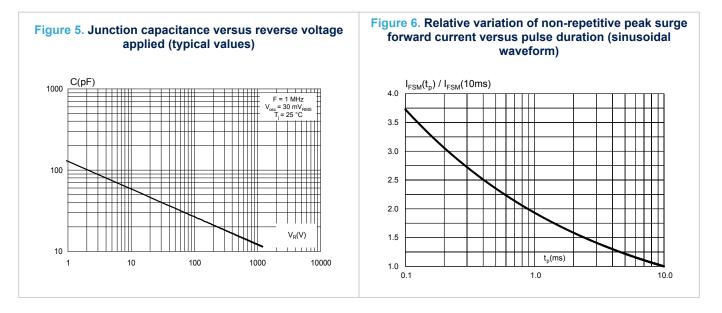


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

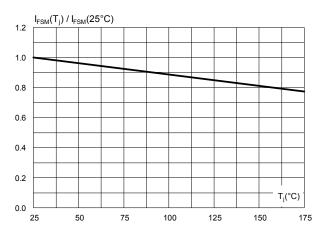


1.0 0.9 0.8 0.7 0.6 Ilse 0.5 0.4 0.3 0.2 0.1 Single pulse + _p(s) ----0.0 1.E-5 1.E-4 1.E-3 1.E-2 1.E-1











2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 HU³PAK package information

Epoxy meets UL94, V0

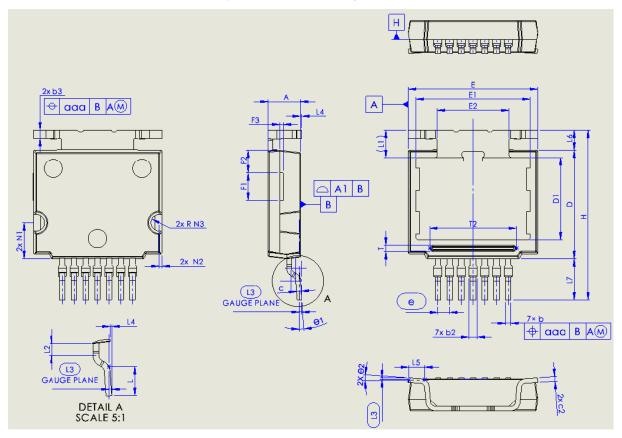


Figure 8. HU³PAK package outline

Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 4. HU³PAK package mechanical data

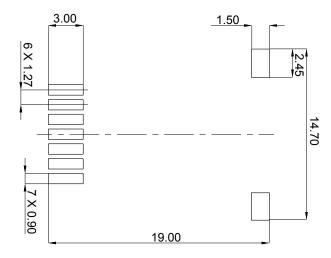
	Dimensions mm					
Ref.						
	Min.	Тур.	Max.			
A	3.40	3.50	3.60			
A1		0.05				
b	0.50	0.60	0.70			
b2	0.50	0.70	1.00			
b3	0.80	0.90	1.00			
С	0.40	0.50	0.60			
c2	0.40	0.50	0.60			
D	11.70	11.80	11.90			
D1	8.80	8.955	9.10			
E	13.90	14.00	14.10			
E1	12.30	12.40	12.50			
E2	7.75	7.80	7.85			
е	BSC 1.27					
Н	18.00	18.58	19.00			
L	2.40	2.52	2.60			
L1		3.05				
L2	0.90	1.00	1.10			
L3		BSC 0.26				
L4	0.075	0.125	0.175			
L5	1.83	1.93	2.03			
L6	2.14	2.24	2.34			
L7	4.44	4.54	4.64			
ааа		0.10				
F1	2.90	3.00	3.10			
F2	2.40	2.50	2.60			
F3	0.25	0.35	0.45			
N1	3.80	3.90	4.00			
N2	0.25	0.30	0.45			
N3	0.80	0.90	1.00			
Т	0.50	0.67	0.70			
T2	9.18	9.38	9.43			
θ1		0°	8°			
θ2		0°	8°			

1. Package outline exclusive of any mold flashes dimensions.

- 2. Package outline exclusive of burr dimensions.
- 3. Max resin gate protrusion: 0.25 mm.
- 4. The planarity of the package backside 50 micron max.
- 5. BSC: basic spacing between centers



Figure 9. HU³PAK recommended footprint (dimensions are in mm)



Note: For packing details you can see technical note TN1173: Packing information for IPAD, protection, rectifiers, thyristors and AC Switches.



3 Ordering information

Table 5. Ordering information

Order code	ode Marking Package Weight		Base qty.	Delivery mode	
STBR3012L2Y-TR	STBR3012L2Y	HU ³ PAK	2.32 g	600	Tape and reel

Revision history

Table 6. Document revision history

Date	Revision	Changes
14-Mar-2024	1	Initial release.

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